

# **Seven-Channel Darlington Array**

#### **FEATURES**

Improved replacement for ULN2803. Fast turn-on and turn-off. TTL/CMOS compatible.

#### **APPLICATIONS**

- Stepping Motor Driver.
- · Relay Driver.
- LED Driver.
- Solenoid Driver.

#### DESCRIPTION

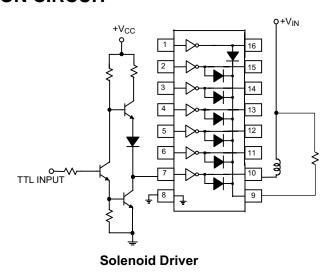
Manufactured with the standard bipolar process, the SS62003 is a high-voltage, high-current 7-channel Darlington array, with each of the output transistors capable of sinking peak load current of 700mA and capable of withstanding at least 35V in the OFF state.

The SS62003 has a  $2.7 \mathrm{K}\Omega$  series base resistor to each Darlington pair and thus allows operation directly with TTL or CMOS logic circuitry operating at a supply voltage of 5V. Outputs of the drivers can be paralleled for higher load current capability.

These make the SS62003 ideally suited for numerous interfaces between low-level logic circuitry and high-power peripheral loads, particularly those beyond the capabilities of standard logic buffers. Typical loads include relays, solenoids, stepping motors, heaters, multiplexed LED, and incandescent displays.

The SS62003 features open collector outputs and integral diodes for inductive load transient suppression.

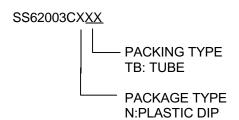
#### TYPICAL APPLICATION CIRCUIT





#### ORDERING INFORMATION

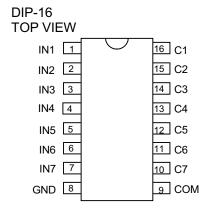
#### PIN CONFIGURATION



Example: SS62003CNTB

→ in DIP-16 Package & Tube

Packing Type



### **ABSOLUTE MAXIMUM RATINGS** (at $T_A = 25^{\circ}C$ )

Output Voltage, V <sub>CE</sub>	35V
Input Voltage, V <sub>IN</sub>	30V
Continuous Collector Current, I <sub>C</sub>	500mA
Continuous Base Current, I <sub>B</sub>	25mA
Power Dissipation, PD (one Darlington pair)	1.0W
(total package)	2.25W
Operating Ambient Temperature Range, T <sub>A</sub>	-20°C to +85°C
Storage Temperature Range, T <sub>S</sub>	-55°C to +150°C

#### PIN DESCRIPTIONS

PIN 1~7: IN1~IN7 - Control signal input pin.

PIN 8: GND - Power ground.

PIN 9: COM - The output pin (Cathode) of freewheeling diode.

PIN 10~16:  $C1\sim C7$  - Each of the pins may individually sink load current from some controlled circuits. The

sunk current should be under 500mA in a continuous mode.



## **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub>= 25°C, unless otherwise specified.)

PARAMETERS	SYMBOL	TEST FIG	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Output Leakage Current	I <sub>CEX</sub>	1	V <sub>CE</sub> =35V,T <sub>A</sub> =25°C			3	^
			V <sub>CE</sub> =35V,T <sub>A</sub> =70°C			50	μΑ
Calla star Fraittar			I <sub>C</sub> =100mA,I <sub>B</sub> =250μA		8.0	1.1	
Collector-Emitter	V <sub>CE(SAT)</sub>	2	I <sub>C</sub> =200mA,I <sub>B</sub> =350μA		0.9	1.3	V
Saturation Voltage			I <sub>C</sub> =350mA,I <sub>B</sub> =500μA		1.0	1.5	
Input Current	I <sub>IN(ON)</sub>	3	V <sub>IN</sub> =3.85V		0.93	1.35	mA
	I <sub>IN(OFF)</sub>	4	I <sub>C</sub> =500μA,T <sub>A</sub> =70°C	50	65		μΑ
Input voltage			V <sub>CE</sub> =2.0V,I <sub>C</sub> =200mA			2.3	
	V <sub>IN(ON)</sub>	5	V <sub>CE</sub> =2.0V,I <sub>C</sub> =250mA			2.4	V
			V <sub>CE</sub> =2.0V,I <sub>C</sub> =300mA			2.5	
Input Capacitance	C <sub>IN</sub>				15	25	pF
Turn-On Delay	t <sub>ON</sub>		0.5 E <sub>IN</sub> to 0.5 E <sub>OUT</sub>		0.25	1.0	μS
Turn-off Delay	t <sub>OFF</sub>		$0.5 E_{\text{IN}}$ to $0.5 E_{\text{OUT}}$		0.25	1.0	μS
Clamp Diode		6	V <sub>R</sub> =35V, T <sub>A</sub> =25°C			3	μΑ
Leakage Current	I <sub>R</sub>		V <sub>R</sub> =35V, T <sub>A</sub> =70°C			50	μΑ
Clamp Diode			1 050 4		4.4	4.0	
Forward Voltage	V <sub>F</sub>	7	I <sub>F</sub> =350mA		1.4	1.8	V

### **TEST CIRCUITS**

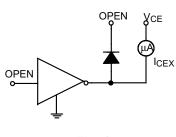


Fig. 1

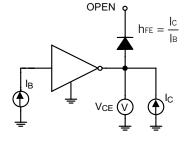


Fig. 2



## **TEST CIRCUITS (cont.)**

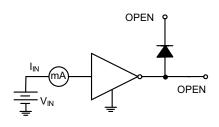


Fig. 3

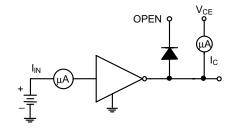


Fig. 4

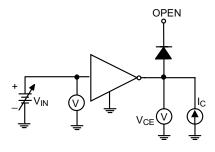


Fig. 5

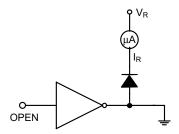
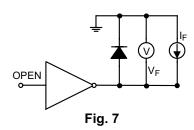
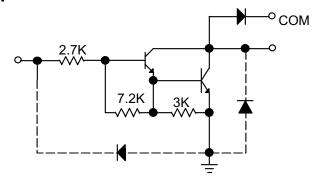


Fig. 6



## **DRIVER CIRCUIT**





### **ALLOWABLE AVERAGE POWER DISSIPATION**

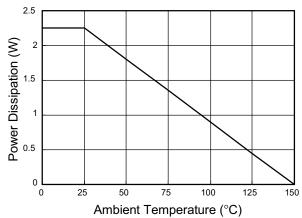
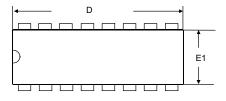
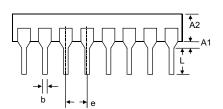


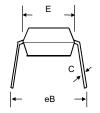
Fig. 8 Power Dissipation vs. Ambient Temperature

#### PHYSICAL DIMENSIONS

#### 16 LEAD PLASTIC DIP (unit: mm)







SYMBOL	MIN	MAX		
A1	0.381	_		
A2	2.92	4.96		
b	0.35	0.56		
С	0.20	0.36		
D	18.66	19.69		
Е	7.62	8.26		
E1	6.09	7.12		
е	2.54(TYP)			
eВ	_	10.92		
L	2.92	3.81		

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